

# NLU3G14

## Triple Schmitt-Trigger Inverter

The NLU3G14 MiniGate™ is an advanced high-speed CMOS triple Schmitt-trigger inverter in ultra-small footprint.

The NLU3G14 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

The NLU3G14 can be used to enhance noise immunity or to square up slowly changing waveforms.

### Features

- High Speed:  $t_{PD} = 4.0$  ns (Typ) @  $V_{CC} = 5.0$  V
- Low Power Dissipation:  $I_{CC} = 1$   $\mu$ A (Max) at  $T_A = 25^\circ$ C
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb-Free Devices

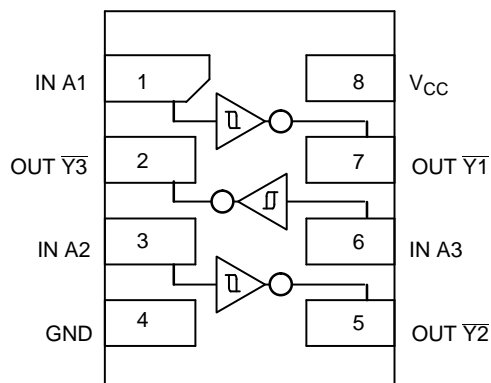


Figure 1. Pinout (Top View)

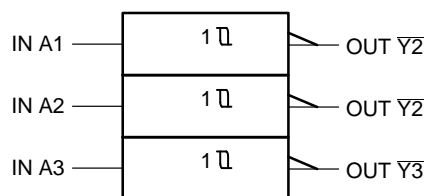


Figure 2. Logic Symbol

| FUNCTION TABLE |   |
|----------------|---|
| A              | Y |
| L              | H |
| H              | L |

### PIN ASSIGNMENT

|   |                 |
|---|-----------------|
| 1 | IN A1           |
| 2 | OUT Y3          |
| 3 | IN A2           |
| 4 | GND             |
| 5 | OUT Y2          |
| 6 | IN A3           |
| 7 | OUT Y1          |
| 8 | V <sub>CC</sub> |



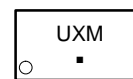
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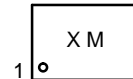
### MARKING DIAGRAMS



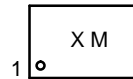
UDFN8  
CASE 517AJ



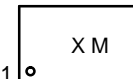
UDFN8  
1.45 x 1.0  
CASE 517BZ



UDFN8  
1.6 x 1.0  
CASE 517BY



UDFN8  
1.95 x 1.0  
CASE 517CA



UX, A or LA = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

## MAXIMUM RATINGS

| Symbol        | Parameter   | Value                  | Unit |
|---------------|---|------------------------|------|
| $V_{CC}$      | DC Supply Voltage   | -0.5 to +7.0           | V    |
| $V_{IN}$      | DC Input Voltage  | -0.5 to +7.0           | V    |
| $V_{OUT}$     | DC Output Voltage   | -0.5 to +7.0           | V    |
| $I_{IK}$      | DC Input Diode Current<br>$V_{IN} < GND$  | -20                    | mA   |
| $I_{OK}$      | DC Output Diode Current<br>$V_{OUT} < GND$  | ±20                    | mA   |
| $I_O$         | DC Output Source/Sink Current   | ±12.5                  | mA   |
| $I_{CC}$      | DC Supply Current Per Supply Pin  | ±25                    | mA   |
| $I_{GND}$     | DC Ground Current per Ground Pin  | ±25                    | mA   |
| $T_{STG}$     | Storage Temperature Range   | -65 to +150            | °C   |
| $T_L$         | Lead Temperature, 1 mm from Case for 10 Seconds   | 260                    | °C   |
| $T_J$         | Junction Temperature Under Bias   | 150                    | °C   |
| MSL           | Moisture Sensitivity  | Level 1                |      |
| $F_R$         | Flammability Rating Oxygen Index: 28 to 34  | UL 94 V-0 @ 0.125 in   |      |
| $V_{ESD}$     | ESD Withstand Voltage<br>Human Body Model (Note 2)<br>Machine Model (Note 3)<br>Charged Device Model (Note 4) | > 2000<br>> 200<br>N/A | V    |
| $I_{LATCHUP}$ | Latchup Performance Above $V_{CC}$ and Below GND at 125°C (Note 5)  | ±500                   | mA   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.
2. Tested to EIA / JESD22-A114-A.
3. Tested to EIA / JESD22-A115-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA / JESD78.

## RECOMMENDED OPERATING CONDITIONS

| Symbol              | Parameter  | Min    | Max                  | Unit |
|---------------------|--|--------|----------------------|------|
| $V_{CC}$            | Positive DC Supply Voltage   | 1.65   | 5.5                  | V    |
| $V_{IN}$            | Digital Input Voltage  | 0      | 5.5                  | V    |
| $V_{OUT}$           | Output Voltage   | 0      | 5.5                  | V    |
| $T_A$               | Operating Free-Air Temperature   | -55    | +125                 | °C   |
| $\Delta t/\Delta V$ | Input Transition Rise or Fall Rate<br>$V_{CC} = 3.3 V \pm 0.3 V$<br>$V_{CC} = 5.0 V \pm 0.5 V$ | 0<br>0 | No Limit<br>No Limit | ns/V |

DC ELECTRICAL CHARACTERISTICS

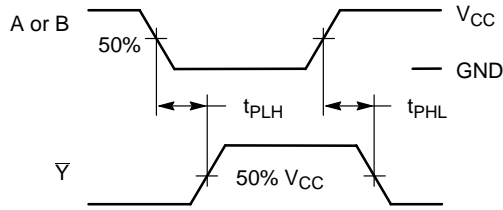
| Symbol          | Parameter                         | Conditions   | V <sub>CC</sub><br>(V) | T <sub>A</sub> = 25 °C |                      |                      | T <sub>A</sub> = +85°C |                      | T <sub>A</sub> = -55°C to +125°C |                      | Unit |
|-----------------|-----------------------------------|--|------------------------|------------------------|----------------------|----------------------|------------------------|----------------------|----------------------------------|----------------------|------|
|                 |                                   |  |                        | Min                    | Typ                  | Max                  | Min                    | Max                  | Min                              | Max                  |      |
| V <sub>T+</sub> | Positive Threshold Voltage        |  | 3.0<br>4.5<br>5.5      | 1.85<br>2.86<br>3.50   | 2.0<br>3.0<br>3.6    | 2.2<br>3.15<br>3.85  |                        | 2.2<br>3.15<br>3.85  |                                  | 2.2<br>3.15<br>3.85  | V    |
| V <sub>T-</sub> | Negative Threshold Voltage        |  | 3.0<br>4.5<br>5.5      | 0.9<br>1.35<br>1.65    | 1.5<br>2.3<br>2.9    | 1.65<br>2.46<br>3.05 | 0.9<br>1.35<br>1.65    |                      | 0.9<br>1.35<br>1.65              |                      | V    |
| V <sub>H</sub>  | Hysteresis Voltage                |  | 3.0<br>4.5<br>5.5      | 0.30<br>0.40<br>0.50   | 0.57<br>0.67<br>0.74 | 1.20<br>1.40<br>1.60 | 0.30<br>0.40<br>0.50   | 1.20<br>1.40<br>1.60 | 0.30<br>0.40<br>0.50             | 1.20<br>1.40<br>1.60 | V    |
| V <sub>OH</sub> | Minimum High-Level Output Voltage | V <sub>IN</sub> ≤ V <sub>T-MIN</sub><br>I <sub>OH</sub> = -50 μA                           | 2.0<br>3.0<br>4.5      | 1.9<br>2.9<br>4.4      | 2.0<br>3.0<br>4.5    |                      | 1.9<br>2.9<br>4.4      |                      | 1.9<br>2.9<br>4.4                |                      | V    |
|                 |                                   | V <sub>IN</sub> ≤ V <sub>T-MIN</sub><br>I <sub>OH</sub> = -4 mA<br>I <sub>OH</sub> = -8 mA | 3.0<br>4.5             | 2.58<br>3.94           |                      |                      | 2.48<br>3.80           |                      | 2.34<br>3.66                     |                      |      |
| V <sub>OL</sub> | Maximum Low-Level Output Voltage  | V <sub>IN</sub> ≥ V <sub>T+MAX</sub><br>I <sub>OL</sub> = 50 μA                            | 2.0<br>3.0<br>4.5      |                        | 0<br>0<br>0          | 0.1<br>0.1<br>0.1    |                        | 0.1<br>0.1<br>0.1    |                                  | 0.1<br>0.1<br>0.1    | V    |
|                 |                                   | V <sub>IN</sub> ≥ V <sub>T+MAX</sub><br>I <sub>OL</sub> = 4 mA<br>I <sub>OL</sub> = 8 mA   | 3.0<br>4.5             |                        |                      | 0.36<br>0.36         |                        | 0.44<br>0.44         |                                  | 0.52<br>0.52         |      |
| I <sub>IN</sub> | Input Leakage Current             | 0 ≤ V <sub>IN</sub> ≤ 5.5 V  | 0 to 5.5               |                        |                      | ±0.1                 |                        | ±1.0                 |                                  | ±1.0                 | μA   |
| I <sub>CC</sub> | Quiescent Supply Current          | 0 ≤ V <sub>IN</sub> ≤ V <sub>CC</sub>  | 5.5                    |                        |                      | 1.0                  |                        | 10                   |                                  | 40                   | μA   |

AC ELECTRICAL CHARACTERISTICS (Input t<sub>r</sub> = t<sub>f</sub> = 3.0 ns)

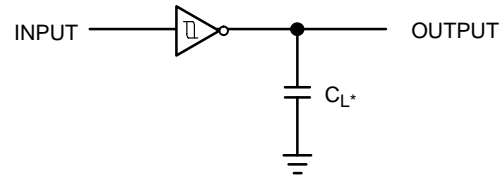
| Symbol                                 | Parameter                              | V <sub>CC</sub><br>(V) | Test Condition         | T <sub>A</sub> = 25 °C |     |      | T <sub>A</sub> = +85°C |      | T <sub>A</sub> = -55°C to +125°C |      | Unit |
|--|--|------------------------|------------------------|------------------------|-----|------|------------------------|------|----------------------------------|------|------|
|  |  |                        |                        | Min                    | Typ | Max  | Min                    | Max  | Min                              | Max  |      |
| t <sub>PLH</sub> ,<br>t <sub>PHL</sub> | Propagation Delay, Input A to Output Y | 3.0 to 3.6             | C <sub>L</sub> = 15 pF |                        | 7.0 | 12.8 | 1.0                    | 15   | 1.0                              | 17   | ns   |
|  |  |                        | C <sub>L</sub> = 50 pF |                        | 8.5 | 16.3 | 1.0                    | 18.5 | 1.0                              | 20.5 |      |
|  |  | 4.5 to 5.5             | C <sub>L</sub> = 15 pF |                        | 4.0 | 8.6  | 1.0                    | 10   | 1.0                              | 11.5 |      |
|  |  |                        | C <sub>L</sub> = 50 pF |                        | 5.5 | 10.6 | 1.0                    | 12   | 1.0                              | 13.5 |      |
| C <sub>IN</sub>                        | Input Capacitance                      |                        |                        |                        | 5.0 | 10   |                        | 10   |                                  | 10   | pF   |
| C <sub>PD</sub>                        | Power Dissipation Capacitance (Note 6) | 5.0                    |                        |                        | 7.0 |      |                        |      |                                  |      | pF   |

6. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

## NLU3G14



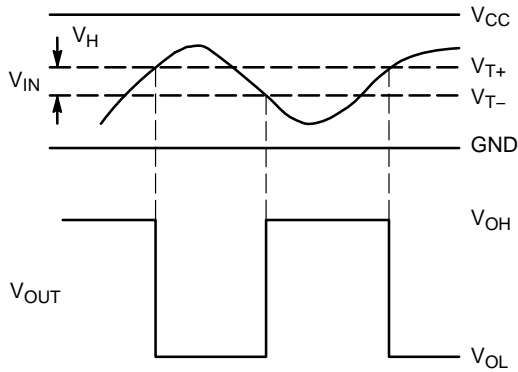
**Figure 3. Switching Waveforms**



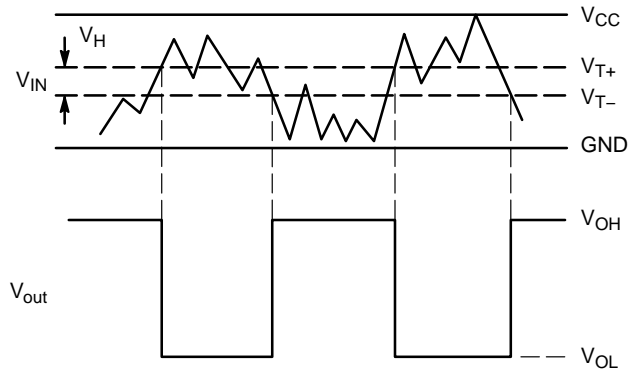
\*Includes all probe and jig capacitance.

A 1-MHz square input wave is recommended for propagation delay tests.

**Figure 4. Test Circuit**



(a) A Schmitt-Trigger Squares Up Inputs With Slow Rise and Fall Times



(b) A Schmitt-Trigger Offers Maximum Noise Immunity

**Figure 5. Typical Schmitt-Trigger Applications**

### ORDERING INFORMATION

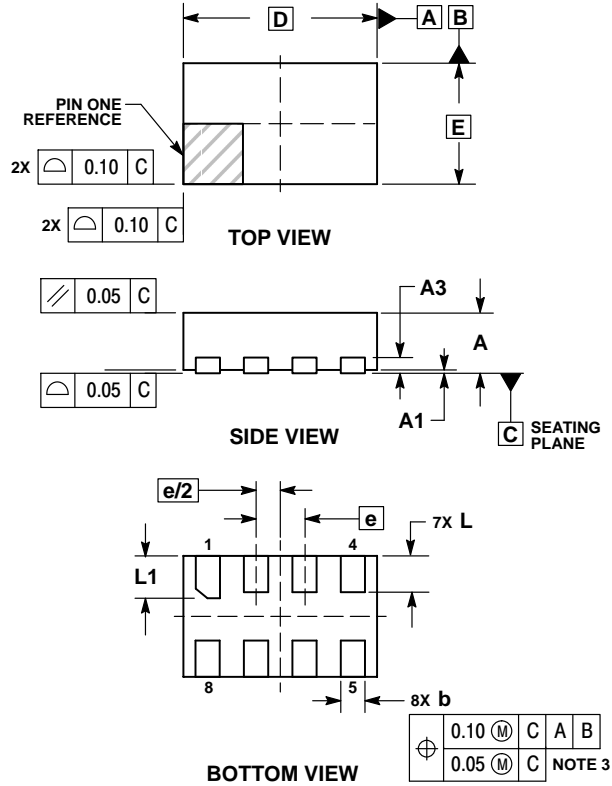
| Device        | Package                               | Shipping†          |
|---------------|---------------------------------------|--------------------|
| NLU3G14MUTAG  | UDFN8<br>(Pb-Free)                    | 3000 / Tape & Reel |
| NLU3G14DMUTCG | UDFN8, 1.95 x 1.0, 0.5P<br>(Pb-Free)  | 3000 / Tape & Reel |
| NLU3G14EMUTCG | UDFN8, 1.6 x 1.0, 0.4P<br>(Pb-Free)   | 3000 / Tape & Reel |
| NLU3G14FMUTCG | UDFN8, 1.45 x 1.0, 0.35P<br>(Pb-Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NLU3G14

## PACKAGE DIMENSIONS

UDFN8 1.6x1.0, 0.4P  
CASE 517BY  
ISSUE O

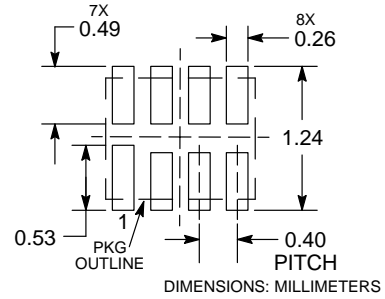


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

| MILLIMETERS |          |      |
|-------------|----------|------|
| DIM         | MIN      | MAX  |
| A           | 0.45     | 0.55 |
| A1          | 0.00     | 0.05 |
| A3          | 0.13 REF |      |
| b           | 0.15     | 0.25 |
| D           | 1.60 BSC |      |
| E           | 1.00 BSC |      |
| e           | 0.40 BSC |      |
| L           | 0.25     | 0.35 |
| L1          | 0.30     | 0.40 |

### RECOMMENDED SOLDERING FOOTPRINT\*

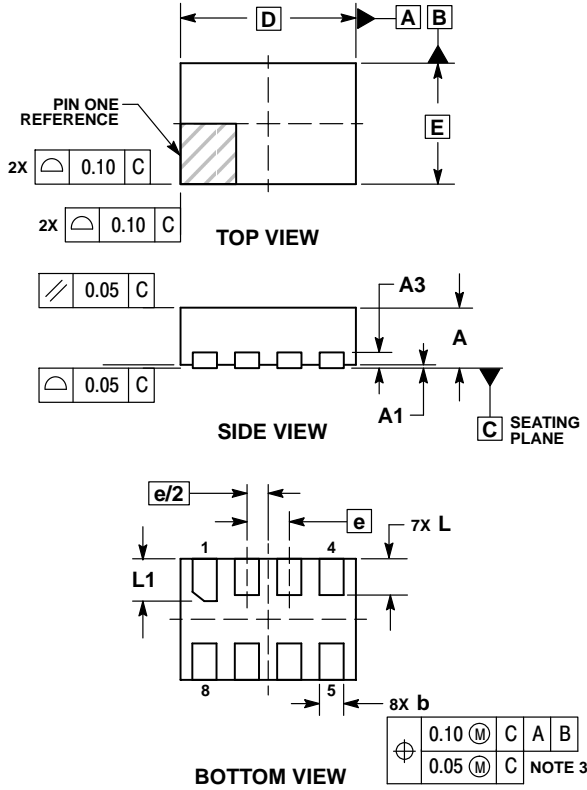


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# NLU3G14

## PACKAGE DIMENSIONS

UDFN8 1.45x1.0, 0.35P  
CASE 517BZ  
ISSUE O

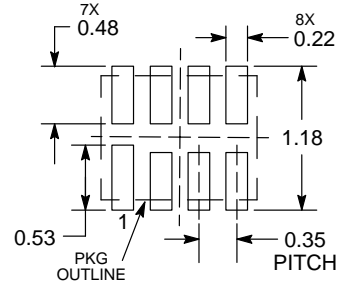


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2. CONTROLLING DIMENSION: MILLIMETERS.
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4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

| DIM | MILLIMETERS |      |
|-----|-------------|------|
|     | MIN         | MAX  |
| A   | 0.45        | 0.55 |
| A1  | 0.00        | 0.05 |
| A3  | 0.13 REF    |      |
| b   | 0.15        | 0.25 |
| D   | 1.45 BSC    |      |
| E   | 1.00 BSC    |      |
| e   | 0.35 BSC    |      |
| L   | 0.25        | 0.35 |
| L1  | 0.30        | 0.40 |

### RECOMMENDED SOLDERING FOOTPRINT\*

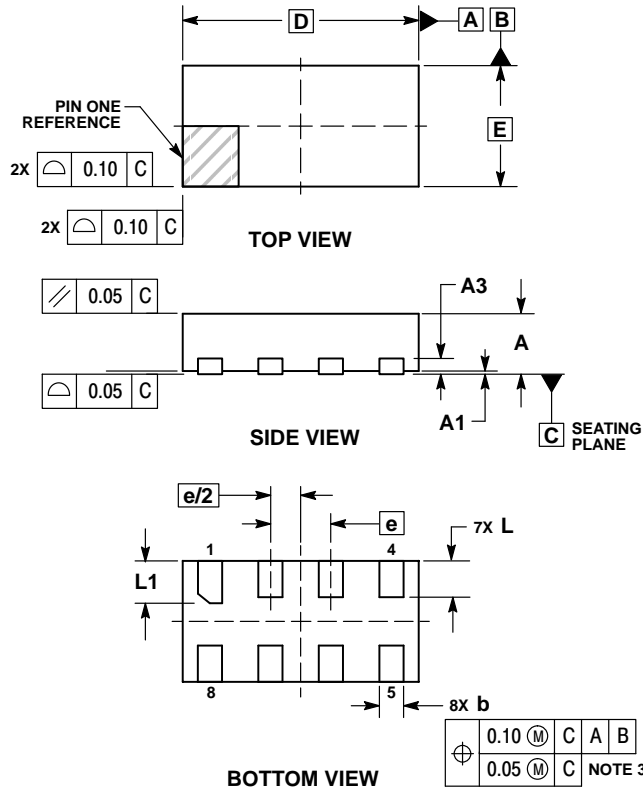


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# NLU3G14

## PACKAGE DIMENSIONS

UDFN8 1.95x1.0, 0.5P  
CASE 517CA  
ISSUE O

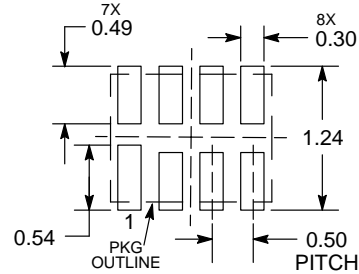


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2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

| DIM | MILLIMETERS |      |
|-----|-------------|------|
|     | MIN         | MAX  |
| A   | 0.45        | 0.55 |
| A1  | 0.00        | 0.05 |
| A3  | 0.13 REF    |      |
| b   | 0.15        | 0.25 |
| D   | 1.95 BSC    |      |
| E   | 1.00 BSC    |      |
| e   | 0.50 BSC    |      |
| L   | 0.25        | 0.35 |
| L1  | 0.30        | 0.40 |

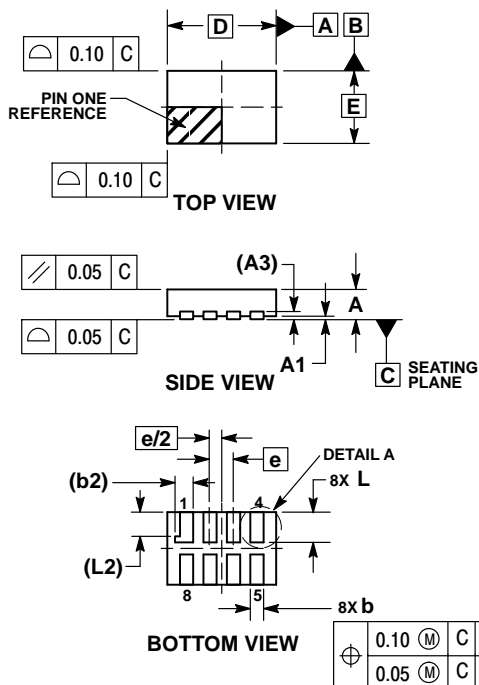
### RECOMMENDED SOLDERING FOOTPRINT\*



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## PACKAGE DIMENSIONS

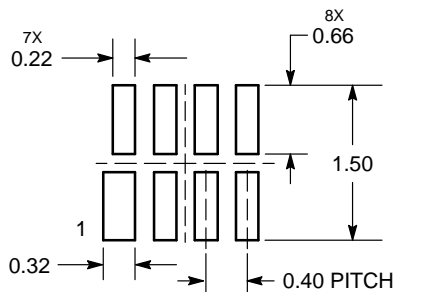
UDFN8 1.8x1.2, 0.4P  
CASE 517AJ  
ISSUE O



- NOTES:
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  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM TERMINAL TIP.
  4. MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH MAY NOT EXCEED 0.03 ONTO BOTTOM SURFACE OF TERMINALS.
  5. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

| MILLIMETERS |       |      |
|-------------|-------|------|
| DIM         | MIN   | MAX  |
| A           | 0.45  | 0.55 |
| A1          | 0.00  | 0.05 |
| A3          | 0.127 | REF  |
| b           | 0.15  | 0.25 |
| b2          | 0.30  | REF  |
| D           | 1.80  | BSC  |
| E           | 1.20  | BSC  |
| e           | 0.40  | BSC  |
| L           | 0.45  | 0.55 |
| L1          | 0.00  | 0.03 |
| L2          | 0.40  | REF  |

### MOUNTING FOOTPRINT SOLDERMASK DEFINED



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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